NCE N-Channel Enhancement Mode Power MOSFET

DESCRIPTION

The NCE0117 uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

GENERAL FEATURES

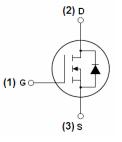
- $V_{DS} = 100V, I_{D} = 17A$
 - $R_{DS(ON)} < 70 \text{m}\Omega$ @ $V_{GS}=10V$ (Typ:56m Ω)
- High density cell design for ultra low Rdson
- Fully characterized Avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

Application

- Power switching application
- Hard Switched and High Frequency Circuits
- Uninterruptible Power Supply

100% UIS TESTED!

100% ΔVds TESTED!



Schematic diagram



Marking and pin Assignment



Package Marking And Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE0117	NCE0117	TO-220-3L	-	-	-

Absolute Maximum Ratings (TA=25°C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	100	V
Gate-Source Voltage	V _G s	±20	V
Drain Current-Continuous	I _D	17	А
Drain Current-Continuous(T _C =100°C)	I _D (100°C)	12	А
Pulsed Drain Current	I _{DM}	60	Α
Maximum Power Dissipation	P _D	55	W
Single pulse avalanche energy (Note 5)	E _{AS}	250	mJ
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 150	$^{\circ}$ C



NCE0117

Thermal Characteristic

Thermal Resistance, Junction-to-Case(Note 2)	R _{eJC}	2.27	°C/W	Ì
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Electrical Characteristics (TA=25°C unless otherwise noted)

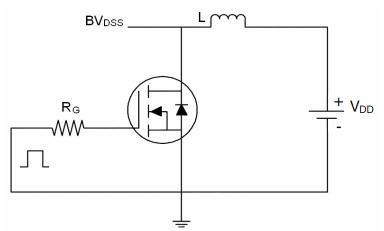
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics		1	·	U.		
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	100	110	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =100V,V _{GS} =0V	-	-	1	μΑ
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)			•			
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =250μA	2	3.2	4	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =5A	-	56	70	mΩ
Forward Transconductance	g FS	V _{DS} =50V,I _D =9A	12	-	-	S
Dynamic Characteristics (Note4)	•	•		•	-	-
Input Capacitance	C _{lss}		-	1350	-	PF
Output Capacitance	C _{oss}	V _{DS} =25V,V _{GS} =0V,	-	240	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.0MHz	-	180	-	PF
Switching Characteristics (Note 4)	<u> </u>			1	L	
Turn-on Delay Time	$t_{d(on)}$		-	13.8	-	nS
Turn-on Rise Time	t _r	V_{DD} =30V, I_{D} =2A, R_{L} =15 Ω	-	9.3	-	nS
Turn-Off Delay Time	$t_{d(off)}$	V_{GS} =10V, R_{G} =2.5 Ω	-	43.8	-	nS
Turn-Off Fall Time	t _f		-	11.4	-	nS
Total Gate Charge	Qg	V 00V/1 0A	-	31		nC
Gate-Source Charge	Q_{gs}	$V_{DS}=30V,I_{D}=3A,$	-	6.4	-	nC
Gate-Drain Charge	Q_{gd}	V _{GS} =10V	-	9.4	-	nC
Drain-Source Diode Characteristics			•	•		•
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =9A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	17	Α
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				
		.1				

Notes:

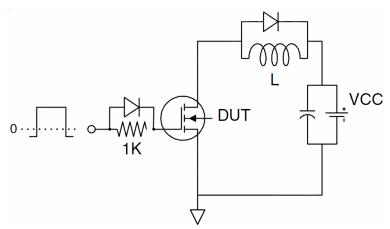
- $\textbf{1.} \ \textbf{Repetitive Rating: Pulse width limited by maximum junction temperature.}$
- 2. Surface Mounted on FR4 Board, t $\, \leqslant \,$ 10 sec.
- 3. Pulse Test: Pulse Width $\, \leqslant \, 300 \, \mu \, \mathrm{s}$, Duty Cycle $\, \leqslant \, 2\%$.
- **4.** Guaranteed by design, not subject to production
- **5.** EAS condition : Tj=25 $^{\circ}\text{C}$,VDD=50V,VG=10V,L=0.5mH,Rg=25 Ω

Test circuit

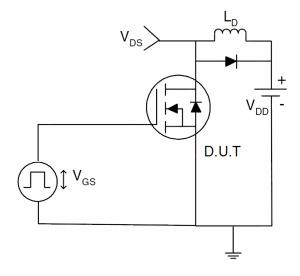
1) E_{AS} test Circuits



2) Gate charge test Circuit:



3) Switch Time Test Circuit:



TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS (Curves)

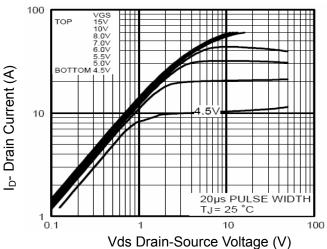


Figure 1 Output Characteristics

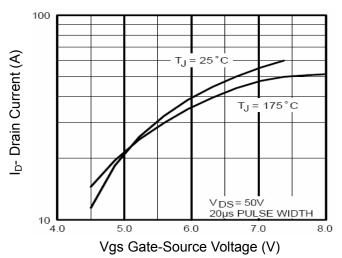
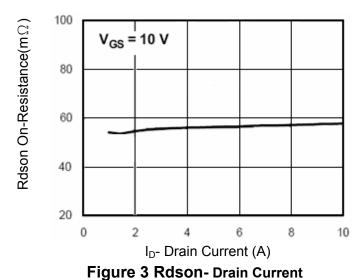


Figure 2 Transfer Characteristics



1.8 V_{os} = 10 V V_{os} = 10 V V_{os} = 10 V V_{os} = 10 V V_{os} = 1.0 V V

Figure 4 Rdson-JunctionTemperature

T_J-Junction Temperature(°C)

25

50

75 100 125 150

0.6 -75

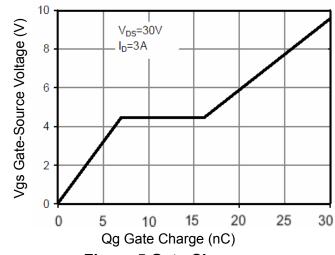


Figure 5 Gate Charge

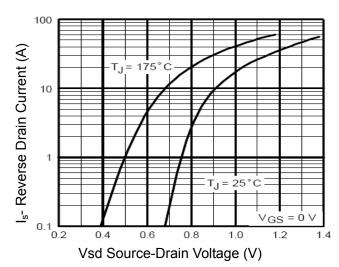


Figure 6 Source- Drain Diode Forward

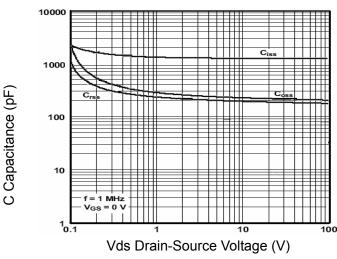


Figure 7 Capacitance vs Vds

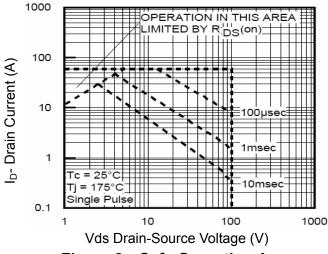


Figure 8 Safe Operation Area

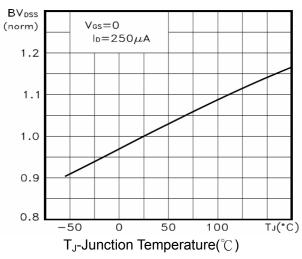


Figure 9 BV_{DSS} vs Junction Temperature

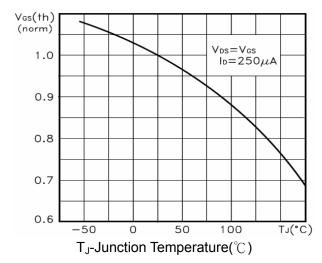


Figure 10 V_{GS(th)} vs Junction Temperature

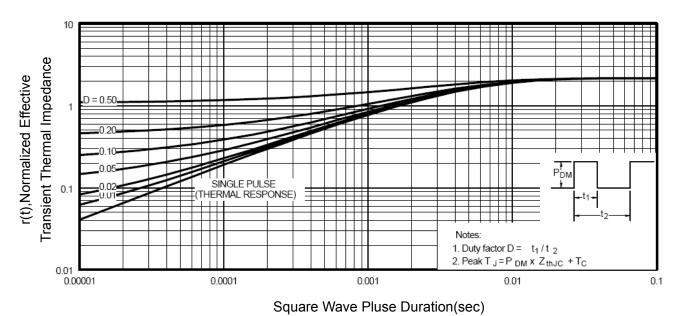
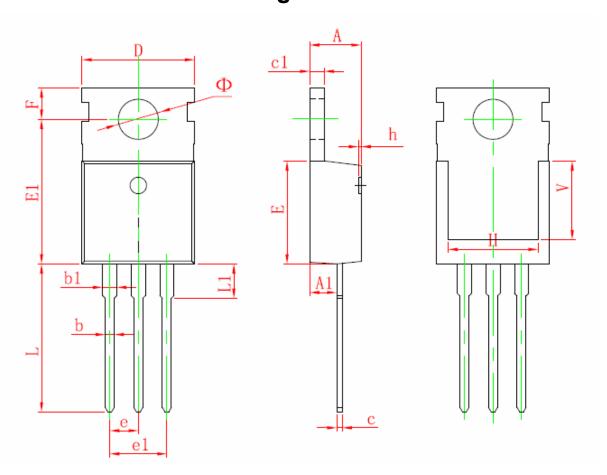


Figure 11 Normalized Maximum Transient Thermal Impedance

TO-220-3L Package Information



Cumbal	Dimensions	In Millimeters	Dimensions In Inches			
Symbol	Min.	Max.	Min.	Max.		
Α	4.400	4.600	0.173	0.181		
A1	2.250	2.550	0.089	0.100		
b	0.710	0.910	0.028	0.036		
b1	1.170	1.370	0.046	0.054		
С	0.330	0.650	0.013	0.026		
c1	1.200	1.400	0.047	0.055		
О	9.910	10.250	0.390	0.404		
E	8.950	9.750	0.352	0.384		
E1	12.650	2.950	0.498	0.116		
е	2.540	TYP.	0.100 TYP.			
e1	4.980	5.180	0.196	0.204		
F	2.650	2.950	0.104	0.116		
Н	7.900	8.100	0.311	0.319		
h	0.000	0.300	0.000	0.012		
L	12.900	13.400	0.508	0.528		
L1	2.850	3.250	0.112	0.128		
V	7.500	REF.	0.295 REF.			
Ф	3.400	3.800	0.134	0.150		

NCE0117

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